ANALOG DEVICES

Dual Matched High Performance Operational Amplifiers

OP-04/OP-14

FEATURES

- **Excellent DC Input Specifications**
- **Matched V_{OS} and CMRR**
- **OP-14 Fits Standard 1458/1558 Sockets**
- **Internally Compensated**
- **Low Noise**
- **Low Drift**
- **Low Cost**
- **0°C/ +70°C and −55°C/ +125°C Models**
- **Silicon-Nitride Passivation**
- **Models with MIL-STD-883 Class B Processing Available From Stock**
- **Available in Die Form**

ORDERING INFORMATION †

T_A = +25°C V_{OS} MAX (mV)	PACKAGE TO-99	TO-100	CERDIP 8-PIN	CERDIP 14-PIN	PLASTIC 8-PIN	OPERATING TEMPERATURE RANGE
0.75	OP14AJ*	OP04AK*	OP14AZ*	OP14AY*	–	MIL
0.75	OP14EJ	–	OP14EZ	OP04EY	OP14EP	COM
2.0	OP14J	OP04K*	OP14Z*	OP04AY	–	MIL
2.0	OP14CJ	OP04CK	OP14CZ	OP04CY	OP14CP	XIND
2.0	–	–	–	–	OP14CS	XIND
5.0	–	OP04BK	–	–	–	MIL
5.0	OP14DJ	–	–	–	OP14DP	XIND

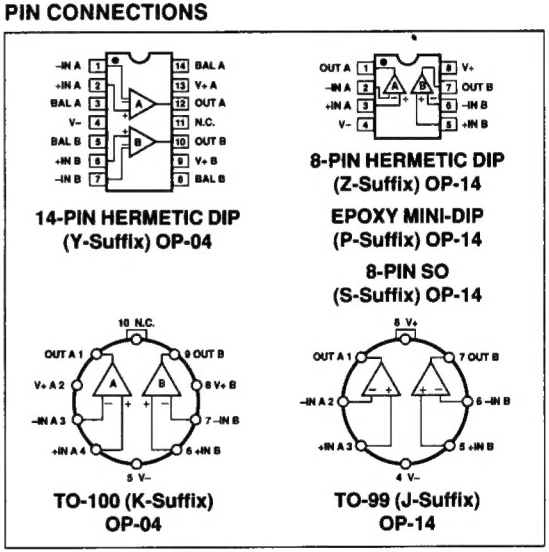
* For devices processed in total compliance to MIL-STD-883, add /883 after part number. Consult factory for 883 data sheet.

† Burn-in is available on commercial and industrial temperature range parts in CerDIP, plastic DIP, and TO-can packages.

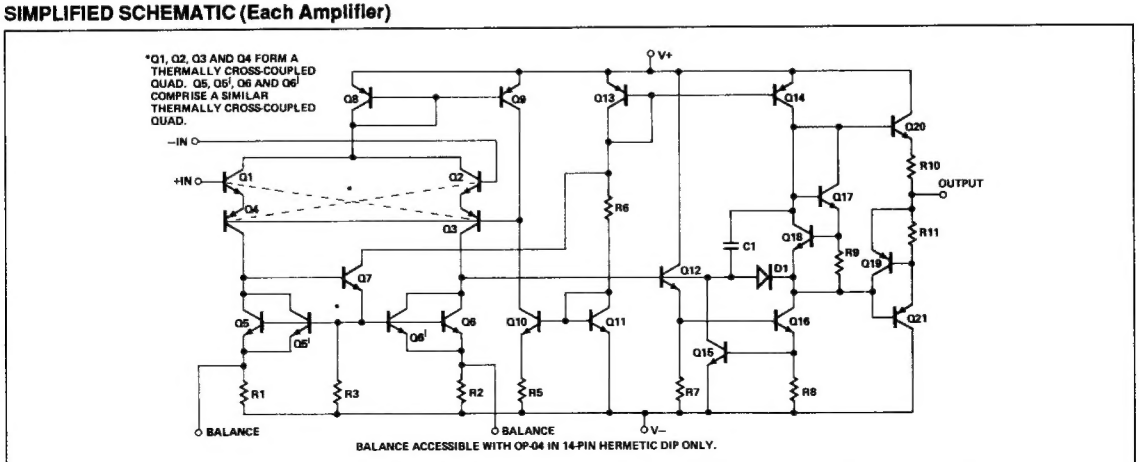
GENERAL DESCRIPTION

The OP-04/OP-14 series of dual general-purpose operational amplifiers provides significant improvements over industry-standard 747 and 1458/1558 (OP-14) types while maintaining pin-for-pin compatibility, ease of application, and low cost. Key specifications, such as V_{OS}, I_{OS}, I_B, CMRR, PSRR and A_{VO}, are guaranteed over the full operating temperature range. Precision Monolithics' exclusive Silicon-Nitride "Triple Passivation" process reduces "popcorn noise". A thermally-symmetrical input stage design provides low TCV_{OS}, TCI_{OS}, and insensitivity to output load conditions. This series is ideal for upgrading existing designs where accuracy improvements are desired. For more stringent requirements, refer to the OP-200, OP-207, OP-220, or OP-221 dual-matched operational amplifier data sheets.

PIN CONNECTIONS



SIMPLIFIED SCHEMATIC (Each Amplifier)



OP-04/OP-14

ABSOLUTE MAXIMUM RATINGS (Note 1)

Supply Voltage ..... ±22V
Differential Input Voltage ..... ±30V
Input Voltage ..... Supply Voltage
Output Short-Circuit Duration ..... Indefinite
Storage Temperature Range
J, K, Y, and Z Packages ..... –65°C to +150°C
P Package ..... –65°C to +125°C
Lead Temperature Range (Soldering, 60 sec) ..... 300°C
Operating Temperature Range
A, Plain, B-Suffix ..... –55°C to +125°C
E-Suffix ..... 0°C to +70°C
C, D-Suffix ..... –40°C to +85°C
Junction Temperature (T_J) ..... –65°C to +150°C

PACKAGE TYPE	Θ_{JA} (Note 2)	Θ_{JC}	UNITS
TO-99 (J)	150	18	°C/W
TO-100 (K)	142	21	°C/W
8-Pin Hermetic DIP (Z)	148	16	°C/W
14-Pin Hermetic DIP (Y)	108	16	°C/W
8-Pin Plastic DIP (P)	103	43	°C/W
8-Pin SO (S)	158	43	°C/W

NOTES:
1. Absolute maximum ratings apply to both DICE and packaged parts, unless otherwise noted.
2. Θ_{JA} is specified for worst case mounting conditions, i.e., Θ_{JA} is specified for device in socket for TO, CerDIP, and P-DIP packages; Θ_{JA} is specified for device soldered to printed circuit board for SO package.

MATCHING CHARACTERISTICS at $V_S = \pm 15V$, $T_A = 25°C$, unless otherwise noted.

			OP-04A OP-04E OP-14A OP-14E			OP-04 OP-04C OP-14 OP-14C			
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Input Offset Voltage Match	ΔV_{OS}	$R_S \leq 20k\Omega$	—	0.3	1	—	1	2	mV
Common-Mode Rejection Ratio Match	$\Delta CMRR$	$V_{CM} = \pm 10V$, $R_S \leq 100\Omega$	94	106	—	94	106	—	dB

MATCHING CHARACTERISTICS at $V_S = \pm 15V$, $-55°C \leq T_A \leq +125°C$ for OP-04A, OP-14A, OP-04 and OP-14, $0°C \leq T_A \leq +70°C$ for OP-04E, OP-14E, $-40°C \leq T_A \leq +85°C$ for OP-04C and OP-14C, unless otherwise noted.

			OP-04A OP-04E OP-14A OP-14E			OP-04 OP-04C OP-14 OP-14C			
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Input Offset Voltage Match	ΔV_{OS}	$R_S \leq 20k\Omega$	—	0.5	1.5	—	1.5	3	mV
Common-Mode Rejection Ratio Match	$\Delta CMRR$	$V_{CM} = \pm 10V$, $R_S \leq 100\Omega$	90	100	—	90	100	—	dB

ELECTRICAL CHARACTERISTICS (Each Amplifier) at $V_S = \pm 15V$, $T_A = 25°C$, unless otherwise noted.

			OP-04A/OP-14A			OP-04/OP-14			OP-04B			
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Input Offset Voltage	V_{OS}	$R_S \leq 20k\Omega$	—	0.3	0.75	—	1	2	—	3	5	mV
Input Offset Current	I_{OS}		—	0.5	5	—	1	5	—	5	25	nA
Input Bias Current	I_B		—	18	50	—	20	75	—	30	100	nA
Input Resistance — Differential-Mode	R_{IN}	(Note 3)	2.0	7.5	—	1.35	7	—	1	5	—	MΩ
Input Voltage Range	IVR		±10	±13	—	±10	±13	—	±10	±13	—	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 10V$ $R_S \leq 20k\Omega$	85	100	—	80	95	—	70	85	—	dB
Power Supply Rejection Ratio	PSRR	$V_S = \pm 5V$ to $\pm 20V$ $R_S \leq 20k\Omega$	—	10	60	—	30	100	—	100	150	μV/V
Output Voltage Swing	V_O	$R_L \geq 2k\Omega$	±12	±13	—	±12	±13	—	±12	±13	—	V

ELECTRICAL CHARACTERISTICS (Each Amplifier) at $V_S = \pm 15V$, $T_A = 25°C$, unless otherwise noted. (Continued)

PARAMETER	SYMBOL	CONDITIONS	OP-04A/OP-14A MIN	OP-04A/OP-14A TYP	OP-04A/OP-14A MAX	OP-04/OP-14 MIN	OP-04/OP-14 TYP	OP-04/OP-14 MAX	OP-04B MIN	OP-04B TYP	OP-04B MAX	UNITS
Large-Signal Voltage Gain	A_{VO}	$R_L \geq 2k\Omega$ $V_O = \pm 10V$	100	250	—	50	200	—	25	200	—	V/mV
Power Consumption (Note 2)	P_d	$V_O = 0V$	—	50	90	—	50	90	—	50	90	mW
Input Noise Voltage	e_{np-p}	0.1Hz to 10Hz	—	0.65	—	—	0.65	—	—	0.65	—	μV_{p-p}
Input Noise Voltage Density	e_n	$f_O = 10Hz$	—	25	—	—	25	—	—	25	—	nV/$\sqrt{Hz}$
		$f_O = 100Hz$	—	22	—	—	22	—	—	22	—	
		$f_O = 1000Hz$	—	21	—	—	21	—	—	21	—	
Input Noise Current	i_{np-p}	0.1Hz to 10Hz	—	12.8	—	—	12.8	—	—	12.8	—	pA_{p-p}
Input Noise Current Density	i_n	$f_O = 10Hz$	—	1.4	—	—	1.4	—	—	1.4	—	pA/$\sqrt{Hz}$
		$f_O = 100Hz$	—	0.7	—	—	0.7	—	—	0.7	—	
		$f_O = 1000Hz$	—	0.4	—	—	0.4	—	—	0.4	—	
Channel Separation	CS		100	—	—	100	—	—	80	—	—	dB
Slew Rate (Note 1)	SR	$R_L = 2k\Omega$, $C_L = 100pF$	0.25	0.5	—	0.25	0.5	—	0.25	0.5	—	V/μs
Large-Signal Bandwidth (Notes 1, 5)		$V_O = 20V_{p-p}$	4	8	—	4	8	—	4	8	—	kHz
Closed-Loop Bandwidth (Note 4)	BW	$A_{VCL} = +1.0$	1.0	1.3	—	1.0	1.3	—	1.0	1.3	—	MHz
Risetime (Note 1)	t_r	$A_V = +1$, $V_{IN} = 50mV_{p-p}$ $R_L = 2k\Omega$, $C_L = 50pF$	—	260	350	—	260	350	—	260	350	ns
Overshoot (Note 1)	OS	$A_V = +1$, $V_{IN} = 50mV_{p-p}$ $R_L = 2k\Omega$, $C_L = 50pF$	—	5	10	—	5	10	—	5	10	%

ELECTRICAL CHARACTERISTICS (Each Amplifier) at $V_S = \pm 15V$, $-55°C \leq T_A \leq +125°C$, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-04A/OP-14A MIN	OP-04A/OP-14A TYP	OP-04A/OP-14A MAX	OP-04/OP-14 MIN	OP-04/OP-14 TYP	OP-04/OP-14 MAX	OP-04B MIN	OP-04B TYP	OP-04B MAX	UNITS
Input Offset Voltage	V_{OS}	$R_S \leq 20k\Omega$	—	0.4	1.5	—	1.2	3	—	3	6	mV
Average Input Offset Voltage Drift (Note 1)	TCV_{OS}	$R_S = 50\Omega$	—	2	8	—	4	10	—	8	20	μV/°C
Input Offset Current	I_{OS}		—	1	10	—	2	10	—	10	50	nA
Average Input Offset Current Drift (Note 1)	TCI_{OS}		—	7.5	120	—	15	250	—	70	500	pA/°C
Input Bias Current	I_B		—	30	60	—	40	100	—	50	200	nA
Input Voltage Range	IVR		±10	±13	—	±10	±13	—	±10	±13	—	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 10V$ $R_S \leq 20k\Omega$	80	100	—	80	95	—	70	85	—	dB
Power Supply Rejection Ratio	PSRR	$V_S = \pm 5V$ to $\pm 20V$ $R_S \leq 20k\Omega$	—	10	60	—	30	100	—	100	150	μV/V
Large-Signal Voltage Gain	A_{VO}	$R_L \geq 2k\Omega$ $V_O = \pm 10V$	50	100	—	25	60	—	25	60	—	V/mV
Output Voltage Swing	V_O	$R_L \geq 2k\Omega$	±12	±13	—	±12	±13	—	±10	±13	—	V

NOTES:
1. Sample tested.
2. Power dissipation per amplifier.
3. Guaranteed by input bias current.
4. Guaranteed by maximum risetime.
5. Guaranteed by minimum slew rate.

ELECTRICAL CHARACTERISTICS (Each Amplifier) at $V_S = \pm 15V$, $T_A = 25°C$, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-04E/OP-14E MIN	OP-04E/OP-14E TYP	OP-04E/OP-14E MAX	OP-04C/OP-14C MIN	OP-04C/OP-14C TYP	OP-04C/OP-14C MAX	OP-14D MIN	OP-14D TYP	OP-14D MAX	UNITS
Input Offset Voltage	V_{OS}	$R_S \leq 20k\Omega$	—	0.3	0.75	—	1	2	—	3	5	mV
Input Offset Current	I_{OS}		—	0.5	5	—	1	5	—	5	25	nA
Input Bias Current	I_B		—	18	50	—	20	75	—	30	100	nA
Input Resistance — Differential-Mode	R_{IN}	(Note 3)	2.0	7.5	—	1.35	7	—	1	5	—	MΩ
Input Voltage Range	IVR		±10	±13	—	±10	±13	—	±10	±13	—	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 10V$ $R_S \leq 20k\Omega$	85	100	—	80	95	—	70	85	—	dB
Power Supply Rejection Ratio	PSRR	$V_S = \pm 5V$ to $\pm 20V$ $R_S \leq 20k\Omega$	—	10	60	—	30	100	—	100	150	μV/V
Output Voltage Swing	V_O	$R_L \geq 2k\Omega$	±12	±13	—	±12	±13	—	±12	±13	—	V
Large-Signal Voltage Gain	A_{VO}	$R_L \geq 2k\Omega$ $V_O = \pm 10V$	100	250	—	50	200	—	25	150	—	V/mV
Power Consumption (Note 2)	P_d	$V_O = 0V$	—	50	90	—	50	90	—	50	90	mW
Input Noise Voltage	e_{np-p}	0.1Hz to 10Hz	—	0.65	—	—	0.65	—	—	0.65	—	μV_{p-p}
Input Noise Voltage Density	e_n	$f_O = 10Hz$ $f_O = 100Hz$ $f_O = 1000Hz$	— — —	25 22 21	— — —	— — —	25 22 21	— — —	— — —	25 22 21	— — —	$nV/\sqrt{Hz}$
Input Noise Current	i_{np-p}	0.1Hz to 10Hz	—	12.8	—	—	12.8	—	—	12.8	—	pA_{p-p}
Input Noise Current Density	i_n	$f_O = 10Hz$ $f_O = 100Hz$ $f_O = 1000Hz$	— — —	1.4 0.7 0.4	— — —	— — —	1.4 0.7 0.4	— — —	— — —	1.4 0.7 0.4	— — —	$pA/\sqrt{Hz}$
Channel Separation	CS		100	—	—	100	—	—	80	—	—	dB
Slew Rate (Note 1)	SR	$R_L = 2k\Omega$, $C_L = 100pF$	0.25	0.5	—	0.25	0.5	—	0.25	0.5	—	V/μs
Large-Signal Bandwidth (Notes 1, 5)		$V_O = 20V_{p-p}$	4	8	—	4	8	—	4	8	—	kHz
Closed-Loop Bandwidth (Note 4)	BW	$A_{VCL} = +1$	0.8	1.3	—	0.8	1.3	—	0.8	1.3	—	MHz
Risetime (Note 1)	t_r	$A_V = +1$, $V_{IN} = 50mV$ $R_L = 2k\Omega$, $C_L = 50pF$	—	260	350	—	260	350	—	260	350	ns
Overshoot (Note 1)	OS	$A_V = +1$, $V_{IN} = 50mV$ $R_L = 2k\Omega$, $C_L = 50pF$	—	5	10	—	5	10	—	5	10	%

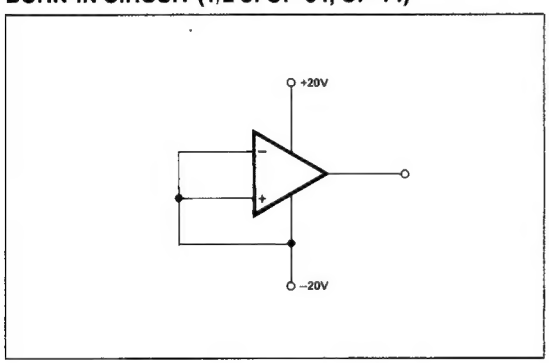
NOTES:
1. Sample tested.
2. Power dissipation per amplifier.
3. Guaranteed by input bias current.
4. Guaranteed by maximum risetime.
5. Guaranteed by minimum slew rate.

ELECTRICAL CHARACTERISTICS (Each Amplifier) at V_S = ±15V, 0°C ≤ T_A ≤ +70°C for E, –40°C to +85° for C and D, unless otherwise noted.

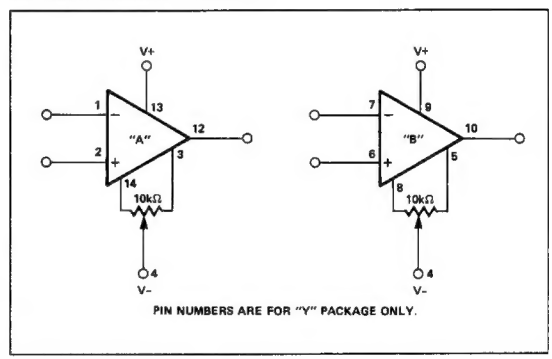
			OP-04E/OP-14E			OP-04C/OP-14C			OP-14D			
PARAMETER	**SYMBOL**	**CONDITIONS**	**MIN**	**TYP**	**MAX**	**MIN**	**TYP**	**MAX**	**MIN**	**TYP**	**MAX**	**UNITS**
Input Offset Voltage	V_{OS}	$R_S \leq 20k\Omega$	—	0.4	1.5	—	1.2	3	—	3	6	mV
Average Input Offset Voltage Drift (Note 1)	TCV_{OS}	$R_S = 50\Omega$	—	2	8	—	4	10	—	8	20	µV/°C
Input Offset Current	I_{OS}		—	1	10	—	2	10	—	10	50	nA
Average Input Offset Current Drift (Note 1)	TCI_{OS}		—	7.5	120	—	15	250	—	70	500	pA/°C
Input Bias Current	I_B		—	30	60	—	40	100	—	50	200	nA
Input Voltage Range	IVR		±10	±13	—	±10	±13	—	±10	±13	—	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 10V$ $R_S \leq 20k\Omega$	80	100	—	80	95	—	70	85	—	dB
Power Supply Rejection Ratio	PSRR	$V_S = \pm 5V$ to $\pm 20V$ $R_S \leq 20k\Omega$	—	10	60	—	30	100	—	100	150	µV/V
Large-Signal Voltage Gain	A_{VO}	$R_L \geq 2k\Omega$ $V_O = \pm 10V$	50	100	—	25	60	—	15	25	—	V/mV
Output Voltage Swing	V_O	$R_L \geq 2k\Omega$	±12	±13	—	±12	±13	—	±10	±13	—	V

NOTES:
1. Sample tested.

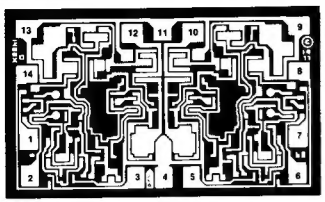
BURN-IN CIRCUIT (1/2 of OP-04, OP-14)



OFFSET ADJUST CIRCUIT



DICE CHARACTERISTICS



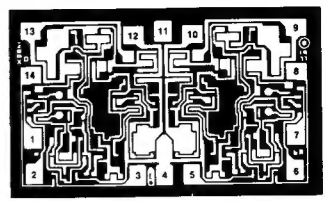
OP-14

1. INVERTING INPUT (A)
2. NONINVERTING INPUT (A)
3. BALANCE (A)
4. V–
5. BALANCE (B)
6. NONINVERTING INPUT (B)
7. INVERTING INPUT (B)
8. BALANCE (B)
9. V+
10. OUTPUT (B)
11. V+
12. OUTPUT (A)
13. V+
14. BALANCE (A)

NOTE: 9, 11 and 13 are internally connected.

DIE SIZE 0.080 × 0.050 inch, 4000 sq. mils
(2.03 × 1.27 mm, 2.58 sq. mm)

OP-04



1. INVERTING INPUT (A)
2. NONINVERTING INPUT (A)
3. BALANCE (A)
4. V–
5. BALANCE (B)
6. NONINVERTING INPUT (B)
7. INVERTING INPUT (B)
8. BALANCE (B)
9. V+ (B)
10. OUTPUT (B)
11. NO CONNECTIONS
12. OUTPUT (A)
13. V+ (A)
14. BALANCE (A)

WAFER TEST LIMITS at $V_S = \pm15V$, $T_A = +25°C$, unless otherwise noted.

PARAMETER	SYMBOL	CONDITIONS	OP-04N OP-14N LIMIT	OP-14G LIMIT	UNITS
Input Offset Voltage	V_{OS}	$R_S \le 20k\Omega$	0.75	2	mV MAX
Input Offset Voltage Match	ΔV_{OS}	$R_S \le 20k\Omega$	1	2	mV MAX
Input Offset Current	I_{OS}		5	5	nA MAX
Input Bias Current	I_B		50	75	nA MAX
Input Voltage Range	IVR		±10	±10	V MIN
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm10V$ $R_S \le 20k\Omega$	85	80	dB MIN
Common-Mode Rejection Ratio Match	ΔCMRR	$V_{CM} = \pm10V$ $R_S \le 100\Omega$	94	94	dB MIN
Power Supply Rejection Ratio	PSRR	$V_S = \pm5V$ to $\pm20V$ $R_S \le 20k\Omega$	60	100	µV/V MAX
Output Voltage Swing	V_O	$R_L \ge 10k\Omega$ $R_L \ge 2k\Omega$	±12 ±12	±12 ±12	V MIN
Large-Scale Voltage Gain	A_{VO}	$R_L \ge 2k\Omega$ $V_O = \pm10V$	100	50	V/mV MIN
Power Consumption (Both Amplifiers)	P_d	$V_O = 0$	170	170	mW MAX
Channel Separation	CS		100	100	dB MIN

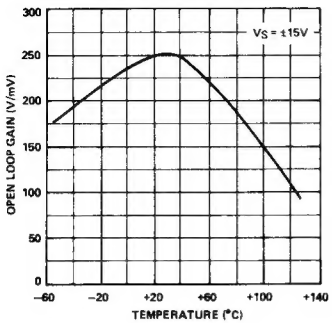
NOTE:
Electrical tests are performed at wafer probe to the limits shown. Due to variations in assembly methods and normal yield loss, yield after packaging is not guaranteed for standard product dice. Consult factory to negotiate specifications based on dice lot qualifications through sample lot assembly and testing.

TYPICAL ELECTRICAL CHARACTERISTICS at $V_S = \pm15V$, $T_A = +25°C$, unless otherwise noted.

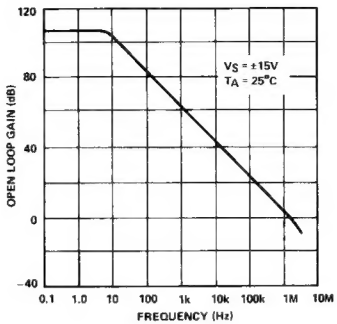
PARAMETER	SYMBOL	CONDITIONS	OP-04N OP-14N LIMIT	OP-04G OP-14G LIMIT	UNITS
Risetime	t_r	$A_V = +1$, $V_{IN} = 50mV$, $R_L = 2k\Omega$, $C_L = 50pF$	200	200	ns
Overshoot	OS	$A_V = +1$, $V_{IN} = 50mV$, $R_L = 2k\Omega$, $C_L = 50pF$	5	5	%
Slew Rate	SR	$R_L = 2k\Omega$, $C_L = 100pF$	0.25	0.25	V/µs

TYPICAL PERFORMANCE CHARACTERISTICS (Each Amplifier)

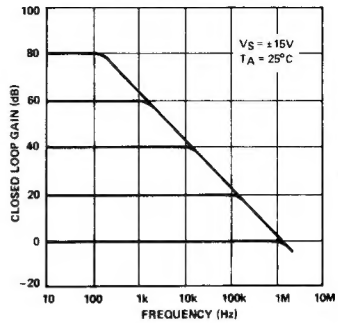
OPEN-LOOP GAIN vs TEMPERATURE



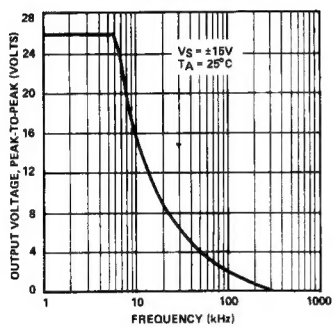
OPEN-LOOP FREQUENCY RESPONSE



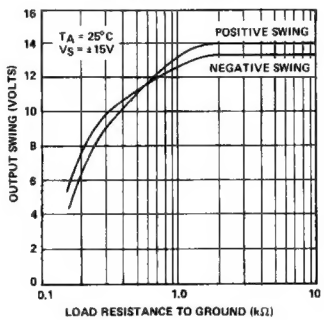
CLOSED-LOOP RESPONSE FOR VARIOUS GAIN CONFIGURATIONS



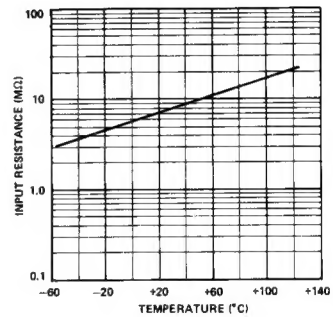
MAXIMUM UNDISTORTED OUTPUT vs FREQUENCY



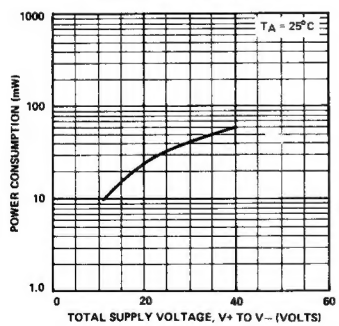
OUTPUT VOLTAGE vs LOAD RESISTANCE



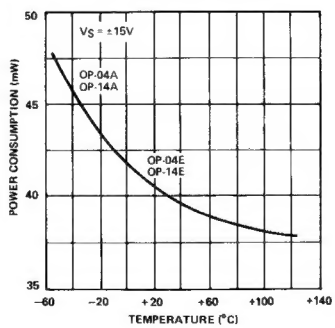
INPUT RESISTANCE vs TEMPERATURE



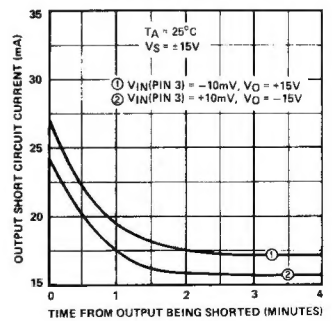
POWER CONSUMPTION vs POWER SUPPLY



POWER CONSUMPTION vs TEMPERATURE

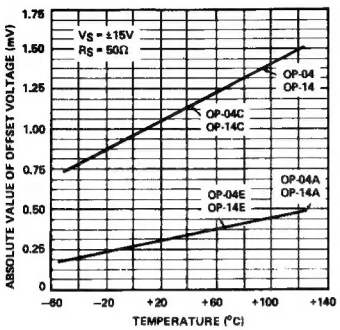


OUTPUT SHORT-CIRCUIT CURRENT vs TIME

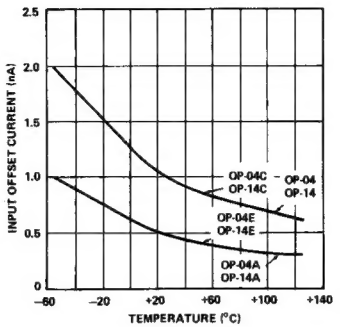


TYPICAL PERFORMANCE CHARACTERISTICS (Each Amplifier)

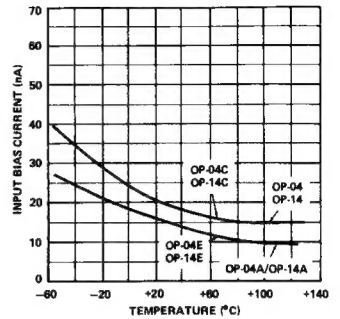
UNTRIMMED OFFSET VOLTAGE vs TEMPERATURE



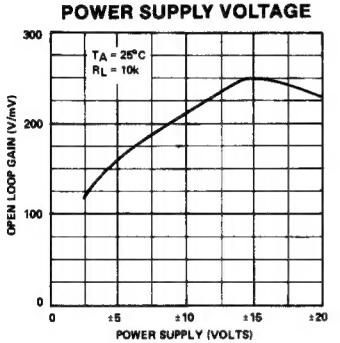
INPUT OFFSET CURRENT vs TEMPERATURE



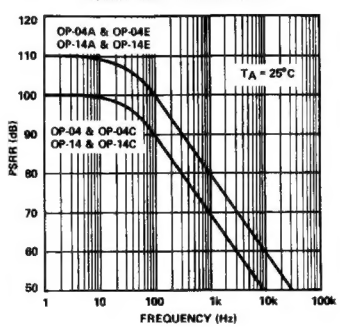
INPUT BIAS CURRENT vs TEMPERATURE



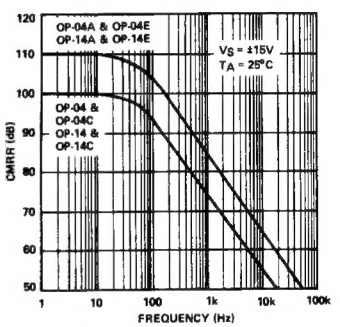
OPEN-LOOP GAIN vs POWER SUPPLY VOLTAGE



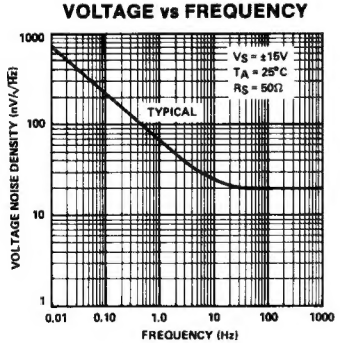
PSRR vs FREQUENCY



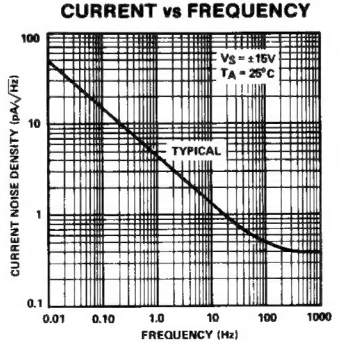
CMRR vs FREQUENCY



INPUT SPOT NOISE VOLTAGE vs FREQUENCY



INPUT SPOT NOISE CURRENT vs FREQUENCY



INPUT WIDEBAND NOISE vs BANDWIDTH (0.1Hz TO FREQUENCY INDICATED)